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Symbol	Description	Min.	Max.	Unit
V_{DD}	Digital supply voltage	-0.3	3.8	V
I_{DD}	Digital supply current	—	120	mA
V_{IO}	Digital pin input voltage (except open drain pins)	-0.3	$V_{DD} + 0.3$ ¹	V
	Open drain pins (PTC6 and PTC7)	-0.3	5.5	V
I_D	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
V_{DDA}	Analog supply voltage	$V_{DD} - 0.3$	$V_{DD} + 0.3$	V

1. Maximum value of V_{IO} (except open drain pins) must be 3.8 V.

2 General

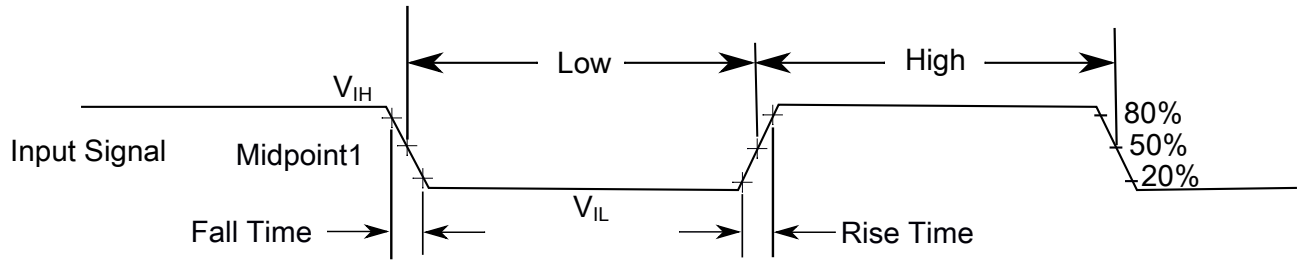
Electromagnetic compatibility (EMC) performance depends on the environment in which the MCU resides. Board design and layout, circuit topology choices, location, characteristics of external components, and MCU software operation play a significant role in EMC performance.

See the following applications notes available on freescale.com for guidelines on optimizing EMC performance.

- *AN2321: Designing for Board Level Electromagnetic Compatibility*
- *AN1050: Designing for Electromagnetic Compatibility (EMC) with HCMOS Microcontrollers*
- *AN1263: Designing for Electromagnetic Compatibility with Single-Chip Microcontrollers*
- *AN2764: Improving the Transient Immunity Performance of Microcontroller-Based Applications*
- *AN1259: System Design and Layout Techniques for Noise Reduction in MCU-Based Systems*

2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is $V_{IL} + (V_{IH} - V_{IL}) / 2$

Figure 2. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume:

1. output pins
 - have $C_L=30\text{pF}$ loads,
 - are slew rate disabled, and
 - are normal drive strength

2.2 Nonswitching electrical specifications

2.2.1 Voltage and current operating requirements

Table 1. Voltage and current operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DD}	Supply voltage	1.71	3.6	V	
V_{DDA}	Analog supply voltage	1.71	3.6	V	
$V_{DD} - V_{DDA}$	V_{DD} -to- V_{DDA} differential voltage	-0.1	0.1	V	
$V_{SS} - V_{SSA}$	V_{SS} -to- V_{SSA} differential voltage	-0.1	0.1	V	
V_{IH}	Input high voltage <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ • $1.71\text{ V} \leq V_{DD} \leq 2.7\text{ V}$ 	$0.7 \times V_{DD}$ $0.75 \times V_{DD}$	— —	V V	
V_{IL}	Input low voltage <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ • $1.71\text{ V} \leq V_{DD} \leq 2.7\text{ V}$ 	— —	$0.35 \times V_{DD}$ $0.3 \times V_{DD}$	V V	
V_{HYS}	Input hysteresis	$0.06 \times V_{DD}$	—	V	
I_{ICIO}	Pin negative DC injection current—single pin <ul style="list-style-type: none"> • $V_{IN} < V_{SS}-0.3\text{V}$ 	-5	—	mA	1

Table continues on the next page...

Table 1. Voltage and current operating requirements (continued)

Symbol	Description	Min.	Max.	Unit	Notes
I_{ICcont}	Contiguous pin DC injection current—regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins <ul style="list-style-type: none"> Negative current injection 	-25	—	mA	
V_{RAM}	V_{DD} voltage required to retain RAM	1.2	—	V	

- All I/O pins are internally clamped to V_{SS} through an ESD protection diode. There is no diode connection to V_{DD} . If V_{IN} greater than V_{IO_MIN} ($= V_{SS}-0.3$ V) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed, then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as $R = (V_{IO_MIN} - V_{IN})/I_{ICIO}$.

2.2.2 LVD and POR operating requirements

Table 2. V_{DD} supply LVD and POR operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{POR}	Falling V_{DD} POR detect voltage	0.8	1.1	1.5	V	
V_{LVDH}	Falling low-voltage detect threshold — high range (LVDV=01)	2.48	2.56	2.64	V	
	Low-voltage warning thresholds — high range					1
V_{LVW1H}	<ul style="list-style-type: none"> Level 1 falling (LVWV=00) 	2.62	2.70	2.78	V	
V_{LVW2H}	<ul style="list-style-type: none"> Level 2 falling (LVWV=01) 	2.72	2.80	2.88	V	
V_{LVW3H}	<ul style="list-style-type: none"> Level 3 falling (LVWV=10) 	2.82	2.90	2.98	V	
V_{LVW4H}	<ul style="list-style-type: none"> Level 4 falling (LVWV=11) 	2.92	3.00	3.08	V	
V_{HYSH}	Low-voltage inhibit reset/recover hysteresis — high range	—	±60	—	mV	
V_{LVDL}	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	
	Low-voltage warning thresholds — low range					1
V_{LVW1L}	<ul style="list-style-type: none"> Level 1 falling (LVWV=00) 	1.74	1.80	1.86	V	
V_{LVW2L}	<ul style="list-style-type: none"> Level 2 falling (LVWV=01) 	1.84	1.90	1.96	V	
V_{LVW3L}	<ul style="list-style-type: none"> Level 3 falling (LVWV=10) 	1.94	2.00	2.06	V	
V_{LVW4L}	<ul style="list-style-type: none"> Level 4 falling (LVWV=11) 	2.04	2.10	2.16	V	
V_{HYSL}	Low-voltage inhibit reset/recover hysteresis — low range	—	±40	—	mV	
V_{BG}	Bandgap voltage reference	0.97	1.00	1.03	V	
t_{LPO}	Internal low power oscillator period — factory trimmed	900	1000	1100	µs	

- Rising thresholds are falling threshold + hysteresis voltage

Table 5. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> at 3.0 V 50 MHz (25 MHz Bus) at 1.8 V 75 MHz (25 MHz Bus) at 3.0 V 75 MHz (25 MHz Bus) 	—	5	6.3	mA	
		—	6.5	7.8	mA	
		—	6.5	7.5	mA	
I _{DD_RUN}	Run mode current — all peripheral clocks enabled, code executing from flash <ul style="list-style-type: none"> at 1.8 V 50 MHz at 3.0 V 50 MHz at 1.8 V 75 MHz at 3.0 V 75 MHz 	—	7.1	8.2	mA	Target IDD
		—	7.1	8	mA	
		—	9.4	10.9	mA	
		—	9.4	10.6	mA	
I _{DD_WAIT}	Wait mode high frequency 75 MHz current at 3.0 V — all peripheral clocks disabled	—	4	5.2	mA	—
I _{DD_WAIT}	Wait mode reduced frequency 50 MHz current at 3.0 V — all peripheral clocks disabled	—	3.4	4.7	mA	—
I _{DD_VLPR}	Very-Low-Power Run mode current 4 MHz at 3.0 V — all peripheral clocks disabled	—	215	437	μA	4 MHz CPU speed, 1 MHz bus speed.
I _{DD_VLPR}	Very-Low-Power Run mode current 4 MHz at 3.0 V — all peripheral clocks enabled	—	313	570	μA	4 MHz CPU speed, 1 MHz bus speed.
I _{DD_VLPW}	Very-Low-Power Wait mode current at 3.0 V — all peripheral clocks disabled	—	149	303	μA	4 MHz CPU speed, 1 MHz bus speed.
I _{DD_VLPW}	Very-Low-Power Wait mode current at 3.0 V — all peripheral clocks enabled	—	244	347	μA	4 MHz CPU speed, 1 MHz bus speed.
I _{DD_STOP}	Stop mode current at 3.0 V <ul style="list-style-type: none"> -40 °C to 25 °C at 50 °C at 70 °C at 85 °C at 105 °C 	—	248	280	μA	—
		—	261	315		
		—	278	333		
		—	307	435		
		—	381	510		
I _{DD_VLPS}	Very-Low-Power Stop mode current at 3.0 V <ul style="list-style-type: none"> -40 °C to 25 °C at 50 °C 	—	2.2	4.3		—
		—	4.2	9.9		

Table continues on the next page...

The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.

2. $V_{DD} = 3.3\text{ V}$, $T_A = 25\text{ °C}$, $f_{OSC} = 10\text{ MHz}$ (crystal), $f_{SYS} = 75\text{ MHz}$, $f_{BUS} = 25\text{ MHz}$
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

2.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

1. Go to www.freescale.com.
2. Perform a keyword search for “EMC design.”

2.2.8 Capacitance attributes

Table 8. Capacitance attributes

Symbol	Description	Min.	Max.	Unit
C_{IN_A}	Input capacitance: analog pins	—	7	pF
C_{IN_D}	Input capacitance: digital pins	—	7	pF

2.3 Switching specifications

2.3.1 Device clock specifications

Table 9. Device clock specifications

Symbol	Description	Min.	Max.	Unit	Notes
Normal run mode					
f_{SYS}	System and core clock	—	48	MHz	
f_{BUS}	Bus clock	—	24	MHz	
f_{FLASH}	Flash clock	—	24	MHz	
f_{LPTMR}	LPTMR clock	—	24	MHz	
High Speed run mode					
f_{SYS}	System and core clock	—	75	MHz	
f_{BUS}	Bus clock	—	25	MHz	
f_{FLASH}	Flash clock	—	25	MHz	
f_{LPTMR}	LPTMR clock	—	25	MHz	

Table continues on the next page...

2.4 Thermal specifications

2.4.1 Thermal operating requirements

Table 11. Thermal operating requirements

Symbol	Description	Min.	Max.	Unit
T _J	Die junction temperature	-40	125	°C
T _A	Ambient temperature	-40	105	°C

NOTE

Maximum T_A can be exceeded only if the user ensures that T_J does not exceed maximum T_J. The simplest method to determine T_J is: $T_J = T_A + \theta_{JA} \times \text{chip power dissipation}$.

2.4.2 Thermal attributes

Table 12. Thermal attributes

Board type	Symbol	Description	48 LQFP	32 LQFP	32 QFN	Unit	Notes
Single-layer (1S)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	81	85	98	°C/W	1
Four-layer (2s2p)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	57	57	34	°C/W	
Single-layer (1S)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	68	72	82	°C/W	
Four-layer (2s2p)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	51	50	28	°C/W	
—	R _{θJB}	Thermal resistance, junction to board	35	33	14	°C/W	2
—	R _{θJC}	Thermal resistance, junction to case	25	25	2.5	°C/W	3
—	Ψ _{JT}	Thermal characterization parameter, junction to package top outside center (natural convection)	7	7	8	°C/W	4

1. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*, or EIA/JEDEC Standard JESD51-6, *Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air)*.
2. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*.

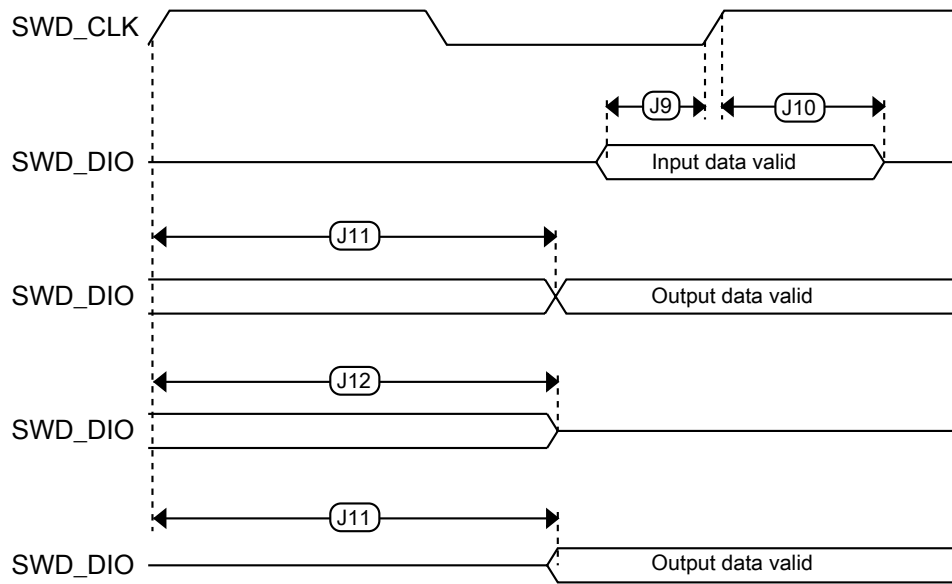


Figure 6. Serial wire data timing

3.2 System modules

There are no specifications necessary for the device's system modules.

3.3 Clock modules

3.3.1 MCG specifications

Table 14. MCG specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{\text{ints_ft}}$	Internal reference frequency (slow clock) — factory trimmed at nominal V_{DD} and 25 °C	—	32.768	—	kHz	
$f_{\text{ints_t}}$	Internal reference frequency (slow clock) — user trimmed	31.25	—	39.0625	kHz	
$\Delta f_{\text{dco_res_t}}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM	—	± 0.3	± 0.6	$\%f_{\text{dco}}$	1

Table continues on the next page...

4. The resulting system clock frequencies must not exceed their maximum specified values. The DCO frequency deviation (Δf_{dco_t}) over voltage and temperature must be considered.
5. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 1.
6. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
7. This specification is based on standard deviation (RMS) of period or frequency.
8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or there is a change from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

3.3.2 Oscillator electrical specifications

3.3.2.1 Oscillator DC electrical specifications

Table 15. Oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{DD}	Supply voltage	1.71	—	3.6	V	
I_{DDOSC}	Supply current — low-power mode (HGO=0) <ul style="list-style-type: none"> • 32 kHz • 4 MHz • 8 MHz • 16 MHz • 24 MHz • 32 MHz 	—	500	—	nA	1
		—	200	—	μA	
		—	300	—	μA	
		—	950	—	μA	
		—	1.2	—	mA	
		—	1.5	—	mA	
I_{DDOSC}	Supply current — high gain mode (HGO=1) <ul style="list-style-type: none"> • 4 MHz • 8 MHz • 16 MHz • 24 MHz • 32 MHz 	—	500	—	μA	1
		—	600	—	μA	
		—	2.5	—	mA	
		—	3	—	mA	
		—	4	—	mA	
C_x	EXTAL load capacitance	—	—	—		2, 3
C_y	XTAL load capacitance	—	—	—		2, 3
R_F	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	M Ω	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	M Ω	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	M Ω	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	M Ω	

Table continues on the next page...

Table 15. Oscillator DC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
R _S	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)	—	0	—	kΩ	
V _{pp} ⁵	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	—	V _{DD}	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)	—	V _{DD}	—	V	

1. V_{DD}=3.3 V, Temperature =25 °C
2. See crystal or resonator manufacturer's recommendation
3. C_x,C_y can be provided by using the integrated capacitors when the low frequency oscillator (RANGE = 00) is used. For all other cases external capacitors must be used.
4. When low power mode is selected, R_F is integrated and must not be attached externally.
5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

3.3.2.2 Oscillator frequency specifications

Table 16. Oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f _{osc_lo}	Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00)	32	—	40	kHz	
f _{osc_hi_1}	Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01)	3	—	8	MHz	
f _{osc_hi_2}	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	—	32	MHz	
f _{ec_extal}	Input clock frequency (external clock mode)	—	—	50	MHz	1, 2
t _{dc_extal}	Input clock duty cycle (external clock mode)	40	50	60	%	

Table continues on the next page...

ADC electrical specifications

1. Typical values assume $V_{DDA} = 3.0\text{ V}$, $\text{Temp} = 25\text{ }^\circ\text{C}$, $f_{ADCK} = 1.0\text{ MHz}$, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had $< 8\ \Omega$ analog source resistance. The R_{AS}/C_{AS} time constant should be kept to $< 1\text{ ns}$.
4. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

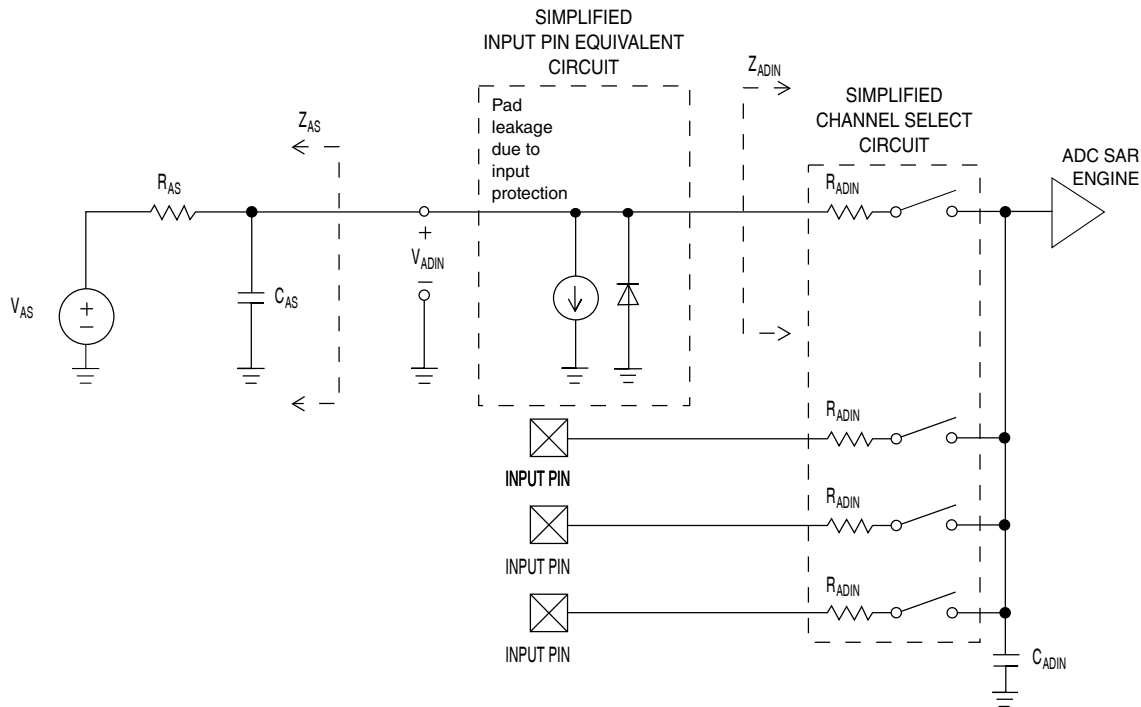


Figure 7. ADC input impedance equivalency diagram

3.6.1.2 16-bit ADC electrical characteristics

Table 22. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Symbol	Description	Conditions ¹ .	Min.	Typ. ²	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	<ul style="list-style-type: none"> • ADLPC = 1, ADHSC = 0 • ADLPC = 1, ADHSC = 1 • ADLPC = 0, ADHSC = 0 • ADLPC = 0, ADHSC = 1 	1.2 2.4 3.0 4.4	2.4 4.0 5.2 6.2	3.9 6.1 7.3 9.5	MHz MHz MHz MHz	$t_{ADACK} = 1/f_{ADACK}$
	Sample Time	See Reference Manual chapter for sample times					

Table continues on the next page...

Table 27. Slave mode DSPI timing (limited voltage range) (continued)

Num	Description	Min.	Max.	Unit
DS9	DSPI_SCK input cycle time	$4 \times t_{BUS}$	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK/2}) - 2$	$(t_{SCK/2}) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	21	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	15	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	15	ns

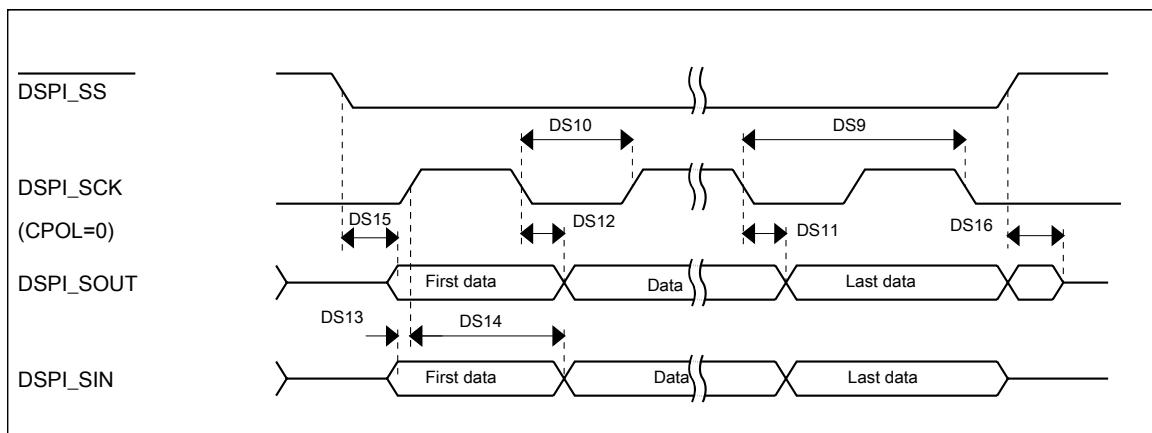


Figure 15. DSPI classic SPI timing — slave mode

3.8.2 DSPI switching specifications (full voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 28. Master mode DSPI timing (full voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	1
	Frequency of operation	—	12.5	MHz	
DS1	DSPI_SCK output cycle time	$4 \times t_{BUS}$	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{SCK/2}) - 4$	$(t_{SCK/2}) + 4$	ns	

Table continues on the next page...



Pinout

48 LQFP	32 QFN	32 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
15	10	10	PTE24	DISABLED		PTE24		FTM0_CH0		I2C0_SCL	EWM_OUT_b	
16	11	11	PTE25	DISABLED		PTE25		FTM0_CH1		I2C0_SDA	EWM_IN	
17	12	12	PTA0	SWD_CLK		PTA0	UART0_CTS_b	FTM0_CH5				SWD_CLK
18	13	13	PTA1	DISABLED		PTA1	UART0_RX	FTM2_CH0	CMP0_OUT	FTM2_QD_PHA	FTM1_CH1	
19	14	14	PTA2	DISABLED		PTA2	UART0_TX	FTM2_CH1	CMP1_OUT	FTM2_QD_PHB	FTM1_CH0	
20	15	15	PTA3	SWD_DIO		PTA3	UART0_RTS_b	FTM0_CH0	FTM2_FLT0	EWM_OUT_b		SWD_DIO
21	16	16	PTA4	NMI_b		PTA4/ LLWU_P3		FTM0_CH1		FTM0_FLT3		NMI_b
22	—	—	VDD	VDD	VDD							
23	—	—	VSS	VSS	VSS							
24	17	17	PTA18	EXTAL0	EXTAL0	PTA18		FTM0_FLT2	FTM_CLKIN0			
25	18	18	PTA19	XTAL0	XTAL0	PTA19	FTM0_FLT0	FTM1_FLT0	FTM_CLKIN1		LPTMR0_ALT1	
26	19	19	PTA20	RESET_b		PTA20						RESET_b
27	20	20	PTB0	ADC0_SE8/ ADC1_SE8	ADC0_SE8/ ADC1_SE8	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0			FTM1_QD_PHA	UART0_RX
28	21	21	PTB1	ADC0_SE9/ ADC1_SE9	ADC0_SE9/ ADC1_SE9	PTB1	I2C0_SDA	FTM1_CH1	FTM0_FLT2	EWM_IN	FTM1_QD_PHB	UART0_TX
29	—	—	PTB2	ADC0_SE10/ ADC1_SE10/ ADC1_DM2	ADC0_SE10/ ADC1_SE10/ ADC1_DM2	PTB2	I2C0_SCL	UART0_RTS_b	FTM0_FLT1		FTM0_FLT3	
30	—	—	PTB3	ADC1_SE2/ ADC1_DP2	ADC1_SE2/ ADC1_DP2	PTB3	I2C0_SDA	UART0_CTS_b			FTM0_FLT0	
31	—	—	PTB16	DISABLED		PTB16		UART0_RX	FTM_CLKIN2		EWM_IN	
32	—	—	PTB17	DISABLED		PTB17		UART0_TX	FTM_CLKIN1		EWM_OUT_b	
33	—	—	PTC0	ADC1_SE11	ADC1_SE11	PTC0	SPI0_PCS4	PDB0_EXTRG		CMP0_OUT	FTM0_FLT0	SPI0_PCS0/ SS_b
34	22	22	PTC1	ADC1_SE3	ADC1_SE3	PTC1/ LLWU_P6	SPI0_PCS3	UART1_RTS_b	FTM0_CH0	FTM2_CH0		
35	23	23	PTC2	ADC0_SE11/ CMP1_IN0	ADC0_SE11/ CMP1_IN0	PTC2	SPI0_PCS2	UART1_CTS_b	FTM0_CH1	FTM2_CH1		
36	24	24	PTC3	CMP1_IN1	CMP1_IN1	PTC3/ LLWU_P7	SPI0_PCS1	UART1_RX	FTM0_CH2	CLKOUT		
37	25	25	PTC4	DISABLED		PTC4/ LLWU_P8	SPI0_PCS0/ SS_b	UART1_TX	FTM0_CH3		CMP1_OUT	
38	26	26	PTC5	DISABLED		PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ALT2			CMP0_OUT	FTM0_CH2
39	27	27	PTC6	CMP0_IN0	CMP0_IN0	PTC6/ LLWU_P10	SPI0_SOUT	PDB0_EXTRG		UART0_RX		I2C0_SCL
40	28	28	PTC7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_SIN			UART0_TX		I2C0_SDA

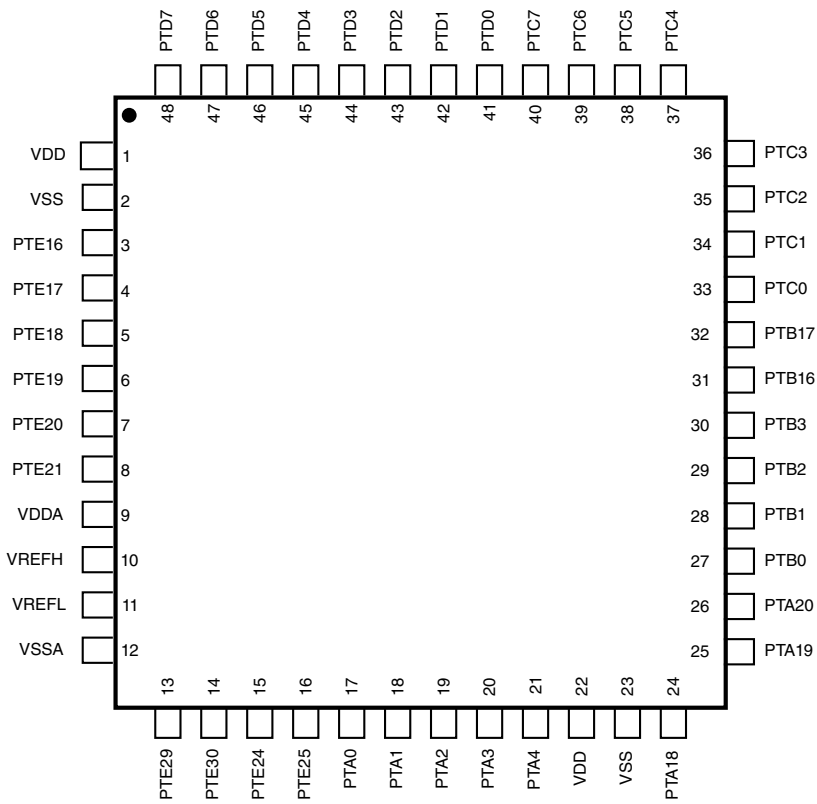


Figure 18. 48 LQFP Pinout Diagram

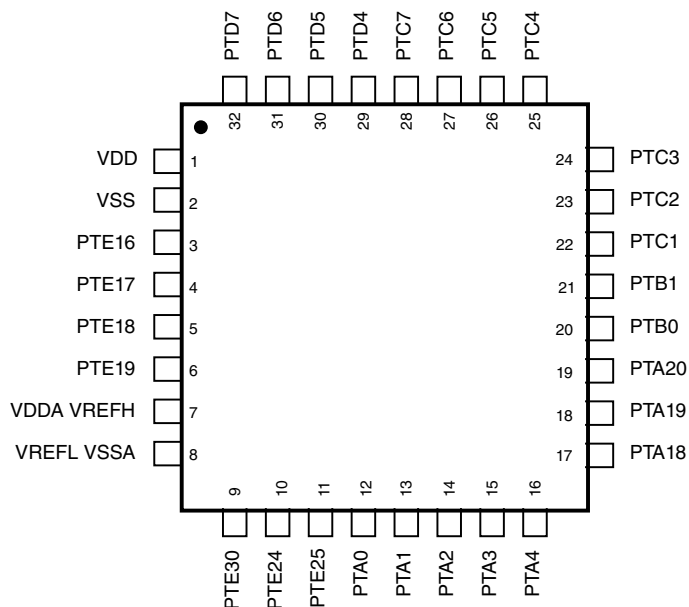


Figure 20. 32 LQFP Pinout Diagram

6 Ordering parts

6.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to www.freescale.com and perform a part number search for the MKV10 device numbers.

7 Part identification

7.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

7.2 Format

Part numbers for this device have the following format:

Q KV## A FFF R T PP CC N

7.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> M = Fully qualified, general market flow P = Prequalification
KV##	Kinetis family	<ul style="list-style-type: none"> KV10
M	Key attribute	<ul style="list-style-type: none"> Z = M0+ core
FFF	Program flash memory size	<ul style="list-style-type: none"> 32 = 32 KB
T	Temperature range (°C)	<ul style="list-style-type: none"> V = -40 to 105
PP	Package identifier	<ul style="list-style-type: none"> FK = 24 QFN (4 mm x 4 mm) LC = 32 LQFP (7 mm x 7 mm) FM = 32 QFN (5 mm x 5 mm) LF = 48 LQFP (7 mm x 7 mm) FT = 48 QFN (10 mm x 10 mm) LH = 64 LQFP (10 mm x 10 mm) LK = 80 LQFP (12 mm x 12 mm) LL = 100 LQFP (14 mm x 14 mm)
CCC	Maximum CPU frequency (MHz)	<ul style="list-style-type: none"> 7 = 75 MHz
N	Packaging type	<ul style="list-style-type: none"> R = Tape and reel (Blank) = Trays

7.4 Example

This is an example part number:

8 Terminology and guidelines

8.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

8.1.1 Example

This is an example of an operating requirement:

Symbol	Description	Min.	Max.	Unit
V _{DD}	1.0 V core supply voltage	0.9	1.1	V

8.2 Definition: Operating behavior

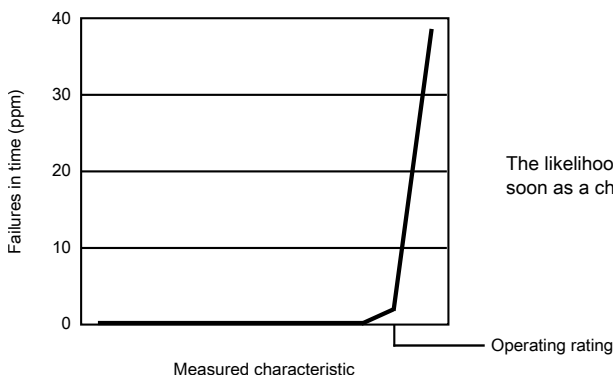
Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

8.2.1 Example

This is an example of an operating behavior:

Symbol	Description	Min.	Max.	Unit
I _{WP}	Digital I/O weak pullup/pulldown current	10	130	μA

8.5 Result of exceeding a rating



The likelihood of permanent chip failure increases rapidly as soon as a characteristic begins to exceed one of its operating ratings.

8.6 Relationship between ratings and operating requirements

<i>Operating rating (min.)</i>		<i>Operating requirement (min.)</i>		<i>Operating requirement (max.)</i>		<i>Operating rating (max.)</i>	
Fatal range Expected permanent failure	Degraded operating range - No permanent failure - Possible decreased life - Possible incorrect operation	Normal operating range - No permanent failure - Correct operation	Degraded operating range - No permanent failure - Possible decreased life - Possible incorrect operation	Fatal range Expected permanent failure			
-∞ Operating (power on) ∞							

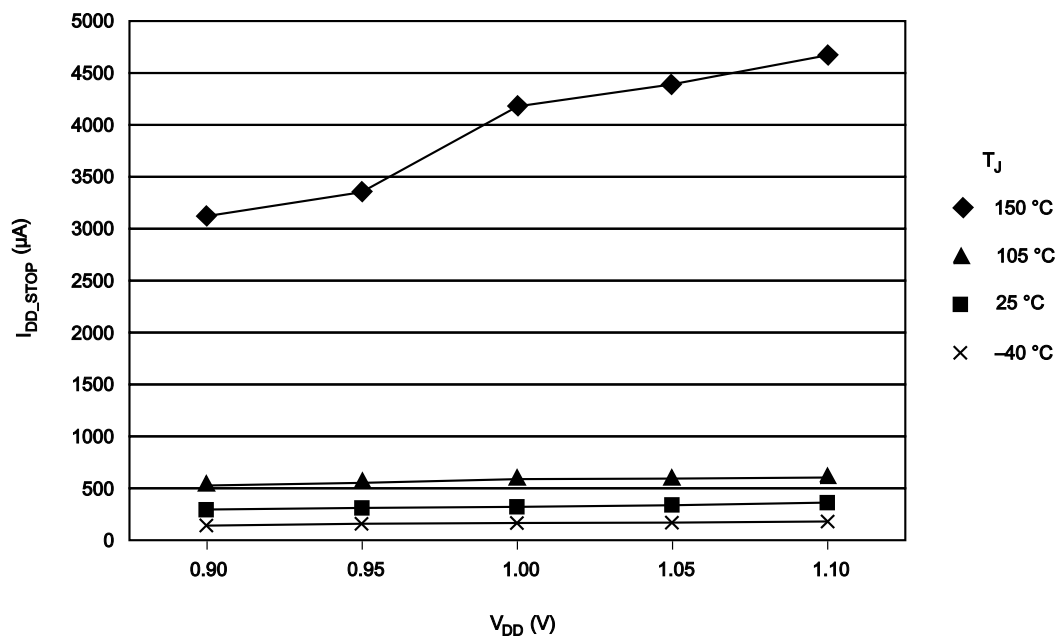
<i>Handling rating (min.)</i>		<i>Handling rating (max.)</i>	
Fatal range Expected permanent failure	Handling range No permanent failure		Fatal range Expected permanent failure
-∞ Handling (power off) ∞			

8.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip’s ratings.
- During normal operation, don’t exceed any of the chip’s operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.

Revision history



8.9 Typical Value Conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T _A	Ambient temperature	25	°C
V _{DD}	3.3 V supply voltage	3.3	V

9 Revision history

The following table provides a revision history for this document.

Table 30. Revision history

Rev. No.	Date	Substantial Changes
3	02/2014	Initial public release
4	02/2015	<ul style="list-style-type: none"> Updated the section "Power consumption operating behaviors" Added a note below the "Thermal operating requirements" table.

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